

**TO-220FL-2L Plastic-Encapsulate Diode****MURF30H60** HYPERFAST RECTIFIER,FRED**MAIN CHARACTERISTICS**

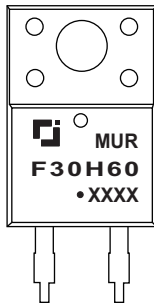
$I_o$	<b>30A</b>
$V_{RRM}$	<b>600V</b>
$T_{rr}$	<b>21ns</b>
$T_j$	<b>175°C</b>
$V_{F(typ)}$	<b>1.55V(@<math>T_j=150^\circ\text{C}</math>)</b>

**FEATURES**

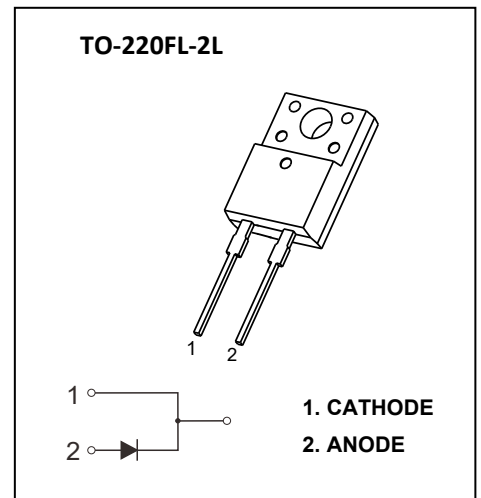
- Ultrafast Recovery Times and Low Recovery Loss
- Low Forward Voltage
- Low Reverse Leakage Current

**APPLICATIONS**

Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

**MARKING**

MURF30H60= Device code  
Solid dot = Green molding compound device  
if none, the normal device  
XXXX = Code

**MAXIMUM RATINGS (  $T_c=25^\circ\text{C}$  unless otherwise noted )**

Symbol	Parameter	MURF30H60	Unit
$V_{RRM}$	Peak Repetitive Reverse Voltage	600	V
$V_R$	DC Blocking Voltage		
$I_{F(AV)}$	Average Forward Current( $T_c=92^\circ\text{C}$ )	30	A
$I_{F(RMS)}$	RMS Forward Current( $T_c=92^\circ\text{C}$ )	42	A
$I_{FSM}$	Non-Repetitive Surge Forward Current (8.3ms )	250	A
$P_D$	Power dissipation	79	W
$R_{\theta JC}$	Thermal Resistance From Junction to Case	1.9	$^\circ\text{C/W}$
$T_j$	Operating Junction Temperature Range	-55 ~ +175	$^\circ\text{C}$
$T_{stg}$	Storage Temperature Range	-55 ~ +175	$^\circ\text{C}$

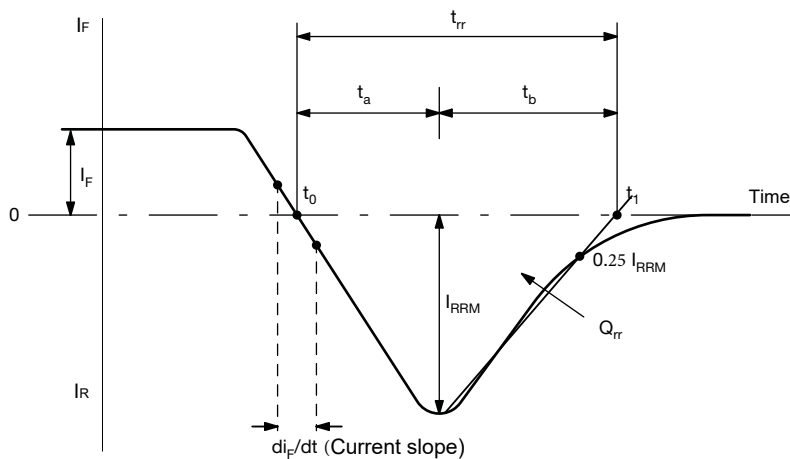
# Typical Characteristics

## ELECTRICAL CHARACTERISTICS ( $T_c=25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$V_{(BR)}$	Reverse Voltage	$I_R=100\mu\text{A}$	600			V
$I_R$	Reverse Current	$V_R=600\text{V}$	$T_J=25^\circ\text{C}$		10	$\mu\text{A}$
			$T_J=150^\circ\text{C}$		1	mA
$V_F$	Forward Voltage	$I_F=30\text{A}$	$T_J=25^\circ\text{C}$	2.7	3	V
			$T_J=150^\circ\text{C}$	1.55		V
$C_{tot}$	Total Capacitance	$V_R=200\text{V}, f=1\text{MHz}$		100		pF
$t_{rr}$	Reverse Recovery time	$I_F=0.5\text{A}, I_R=1\text{A}, I_{rr}=0.25\text{A}$		32		ns
		$I_F=1\text{A}, V_R=30\text{V}, di_F/dt = 200\text{A/us}$		21		ns

## ELECTRICAL CHARACTERISTICS ( $T_c=25^\circ\text{C}$ unless otherwise specified)

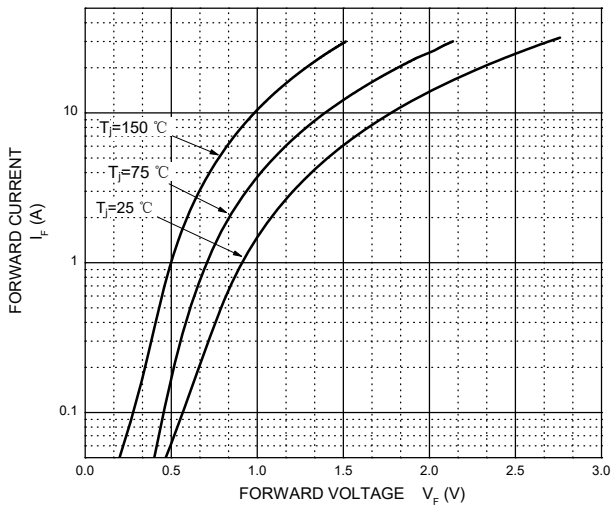
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$t_{rr}$	Reverse Recovery Time	$I_F=30\text{A}, V_R=400\text{V}, di_F/dt=200\text{A}/\mu\text{s}$		29		ns
$I_{RRM}$	Max. Reverse Recovery Current			1.9		A
$Q_{rr}$	Reverse Recovery Charge			32		nC
$t_{rr}$	Reverse Recovery Time	$I_F=30\text{A}, V_R=400\text{V}, di_F/dt=200\text{A}/\mu\text{s}, T_J=125^\circ\text{C}$		60		ns
$I_{RRM}$	Max. Reverse Recovery Current			6		A
$Q_{rr}$	Reverse Recovery Charge			201		nC
$t_{rr}$	Reverse Recovery Time	$I_F=30\text{A}, V_R=400\text{V}, di_F/dt=600\text{A}/\mu\text{s}, T_J=125^\circ\text{C}$		39		ns
$I_{RRM}$	Max. Reverse Recovery Current			14		A
$Q_{rr}$	Reverse Recovery Charge			359		nC



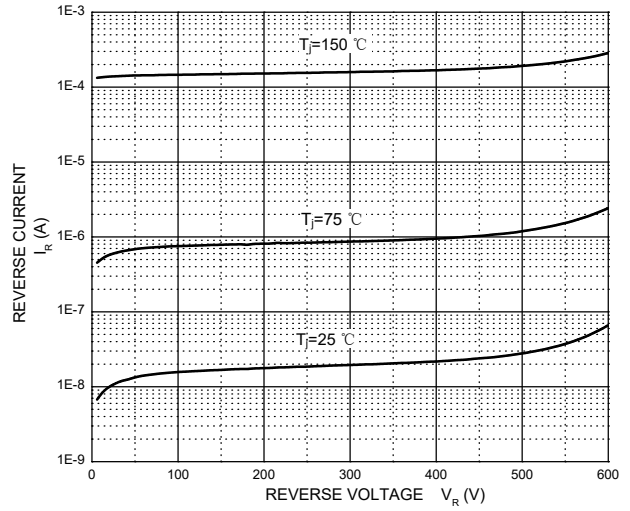
Reverse Recovery Waveform and Definitions

# Typical Characteristics

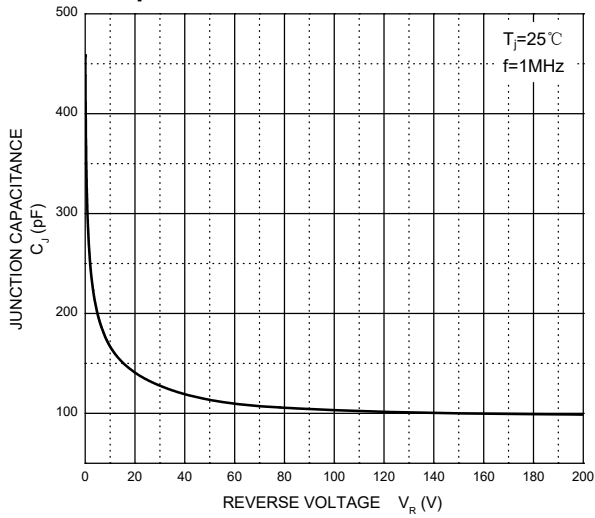
### Forward Characteristics



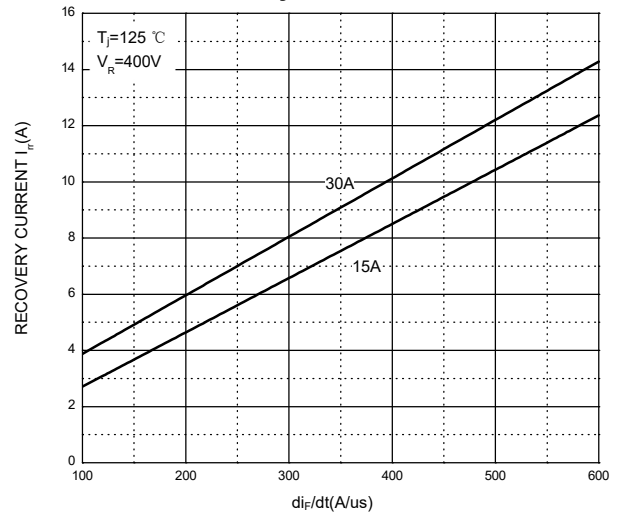
### Reverse Characteristics



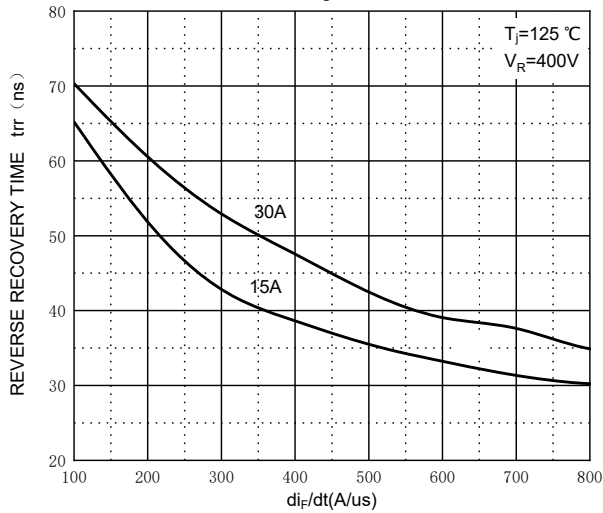
### Capacitance Characteristics Per Diode



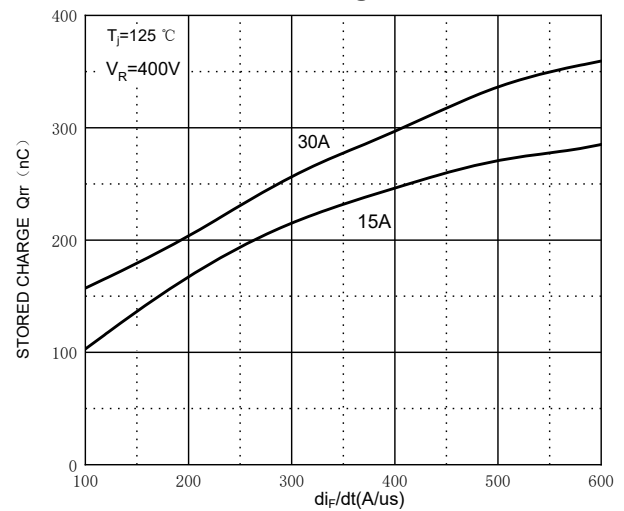
### Recovery Current vs. $di_F/dt$



### Reverse Recovery Time vs. $di_F/dt$

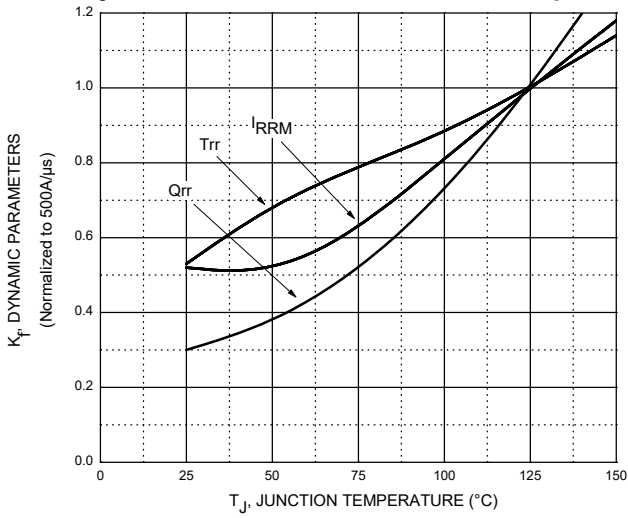


### Stored Charge vs. $di_F/dt$

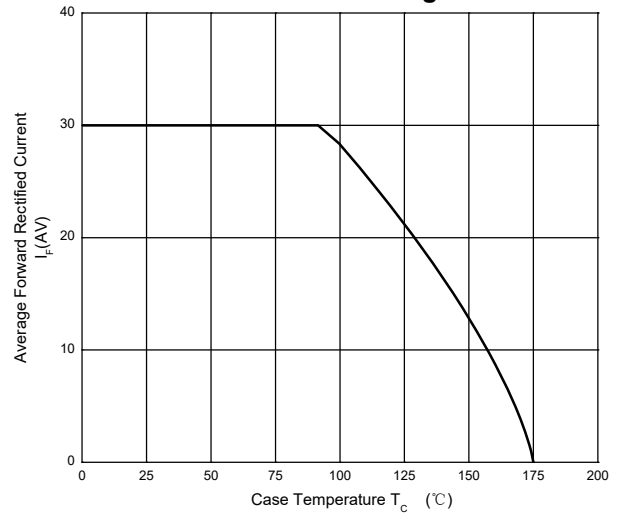


# Typical Characteristics

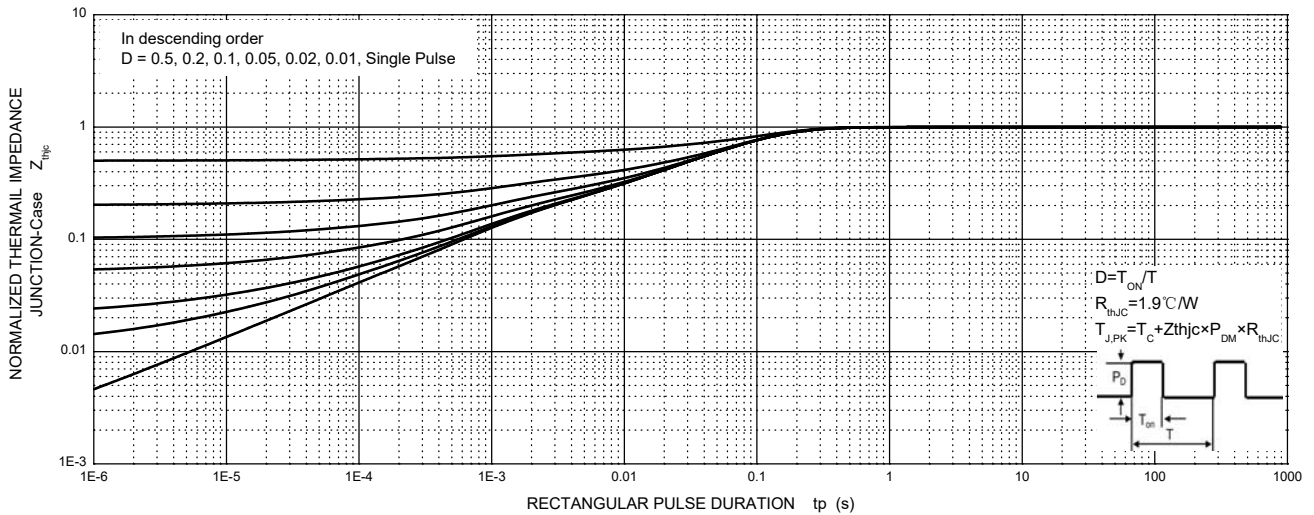
### Dynamic Parameters vs. Junction Temperature



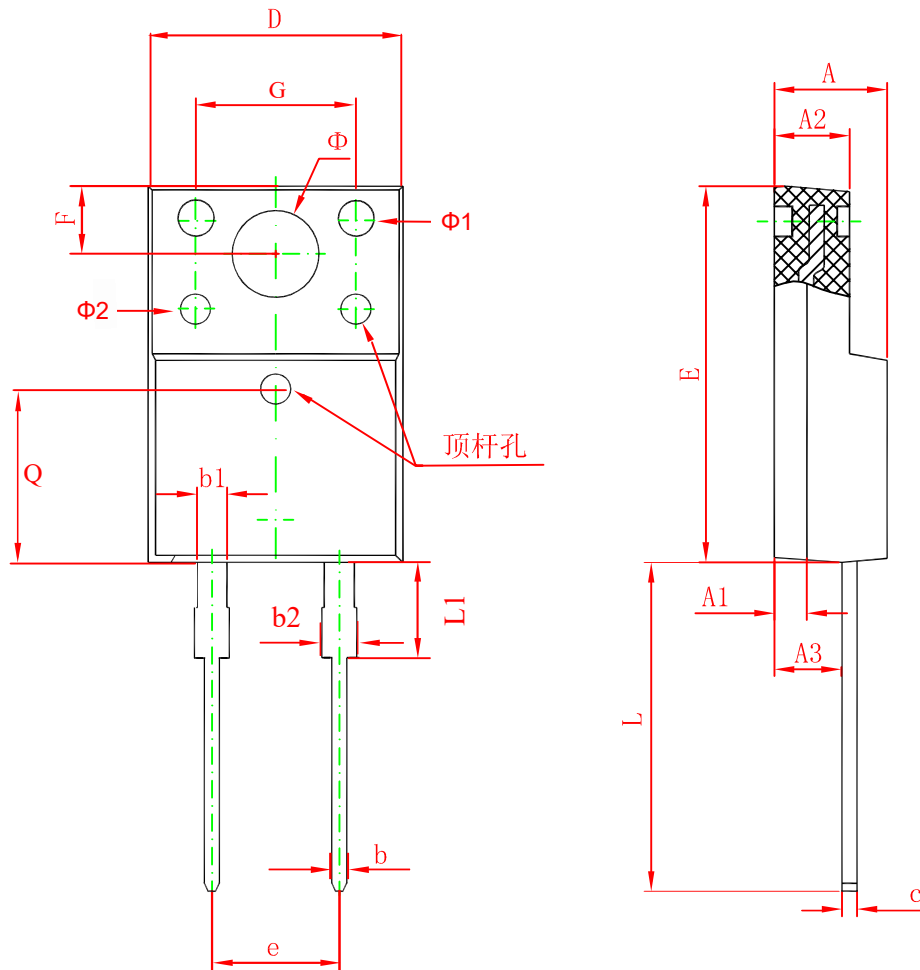
### Current Derating



### MURF30H60 Transient Thermal Impedance, Junction-Case



# TO-220FL-2L Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	4.50	4.90	0.177	0.193
A1	0.38	0.48	0.015	0.019
A2	2.34	2.74	0.092	0.108
A3	2.66	2.86	0.105	0.113
b	0.75	0.85	0.030	0.033
b1	1.24	1.34	0.049	0.053
b2	1.28	1.43	0.050	0.056
c	0.45	0.60	0.018	0.024
D	9.96	10.36	0.392	0.408
e	5.08 TYP.		0.200 TYP.	
E	15.67	16.07	0.617	0.633
F	3.20	3.40	0.126	0.134
G	6.90	7.10	0.272	0.280
L	12.76	13.16	0.502	0.518
L1	-	3.33	-	0.131
Q	6.47 REF.		0.255 REF.	
Φ	3.00	3.38	0.118	0.133
Φ1	1.40	1.60	0.055	0.063
Φ2	0.95	1.05	0.037	0.041